SILICON (Si) POWER MOSFET ▲ CEU20P06



CEU20P06

-60V ▲ 105mΩ ▲ -13A ▲ Si MOSFET

SILICON Si MOSFET ▲ SMD type P-channel enhancement mode UL94V-0 rated flame retardant epoxy TO252 (DPAK) package ▲ MSL 3 Super high dense cell density for extremely low R_{DS(ON)} High power and current handling capability





FREE

RoHS

REACH

MAXIMUM RATINGS

Parameter ($T_c = 25^{\circ}C$, unless otherwise noted)		Characteristics
Drain-Source Voltage	V _{DS}	-60V
Gate-Source Voltage	V _{GS}	±20V
Continuous Drain Current	I _D	-13A
Pulsed Drain Current Note 1	I _{DM}	-52A
Maximum Power Dissipation at T _c = 25°C	PD	42W
Power Dissipation Derating above 25°C	ΔP _D	0.28W/°C
Operating and Storage Temperature Range	T _J , T _{STG}	-55°C to +175°C

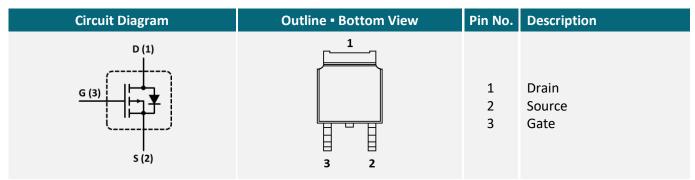
THERMAL CHARACTERISTICS

Parameter	Symbol	Limit
Thermal Resistance, Junction-to-Case	R _{TH_JC}	3.5°C/W
Thermal Resistance, Junction-to-Ambient Note 2	R _{TH_JA}	50°C/W

APPLICATIONS

DC/DC	DC	Load	Power	USB
Converter	Fan	Switches	Banks	Storage
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PIN DESCRIPTION



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ELECTRICAL CHARACTERISTICS A T_c = 25°C, unless otherwise noted

ltem	Condition	Symbol	Min.	Тур.	Max.	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_{D} = -250 \mu A$	BV _{DSS}	-60			V
Zero Gate Voltage Drain Current	$V_{DS} = -48V$, $V_{GS} = 0V$	I _{DSS}			-1	μA
Gate Body Leakage Current, Forward	$V_{GS} = 20V$, $V_{DS} = 0V$	I _{GSSF}			100	nA
Gate Body Leakage Current, Reverse	V_{GS} = -20V, V_{DS} = 0V	I _{GSSR}			-100	nA
On Characteristics Note 4						
Gate Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = -250 \mu A$	V _{GS(th)}	-1		-3	V
Static Drain-Source On-Resistance	$V_{GS} = -10V, I_{D} = -9A$	R _{DS(ON)}		105	125	mΩ
Static Drain-Source On-Resistance	$V_{GS} = -4.5V, I_{D} = -7A$	R _{DS(ON)}		140	175	mΩ
Dynamic Characteristics Note 4						
Input Capacitance	V_{DS} = -30V, V_{GS} = 0V, f = 1MHz	C _{ISS}		615		рF
Output Capacitance	V_{DS} = -30V, V_{GS} = 0V, f = 1MHz	Coss		140		pF
Reverse Transfer Capacitance	V_{DS} = -30V, V_{GS} = 0V, f = 1MHz	C _{RSS}		45		pF
Switching Characteristics Note 4						
Turn-On Delay Time	V_{DD} = -30V, V_{GS} = -10V, I_{D} = -1A, $R_{\text{G(ext)}}$ = 6 Ω	t _{D(ON)}		11	22	ns
Turn-On Rise Time	V_{DD} = -30V, V_{GS} = -10V, I_{D} = -1A, $R_{\text{G(ext)}}$ = 6 Ω	t _R		4.5	9	ns
Turn-Off Delay Time	V_{DD} = -30V, V_{GS} = -10V, I_{D} = -1A, $R_{\text{G(ext)}}$ = 6 Ω	t _{D(OFF)}		50	100	ns
Turn-Off Fall Time	V_{DD} = -30V, V_{GS} = -10V, I_{D} = -1A, $R_{\text{G(ext)}}$ = 6 Ω	t _F		15	30	ns
Total Gate Charge	V_{DS} = -30V, V_{GS} = -10V, I_D = -3.7A	Q _G		17	22	nC
Gate Source Charge	V_{DS} = -30V, V_{GS} = -10V, I_D = -3.7A	Q _{GS}		2		nC
Gate Drain Charge	V_{DS} = -30V, V_{GS} = -10V, I_{D} = -3.7A	\mathbf{Q}_{GD}		4		nC
Drain-Source Diode Characteristics a	nd Maximum Ratings					
Drain-Source Diode Forward Current ^{Note 2}		I _S			-13	А
Drain-Source Diode Forward Voltage ^{Note 3}	V _{GS} = 0V, I _S = -13A	V_{SD}			-1.3	V

Notes

1: Repetitive Rating: Pulse width limited by maximum junction temperature

2: Surface Mounted on FR4 Board, $t \le 10$ sec.

3: Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

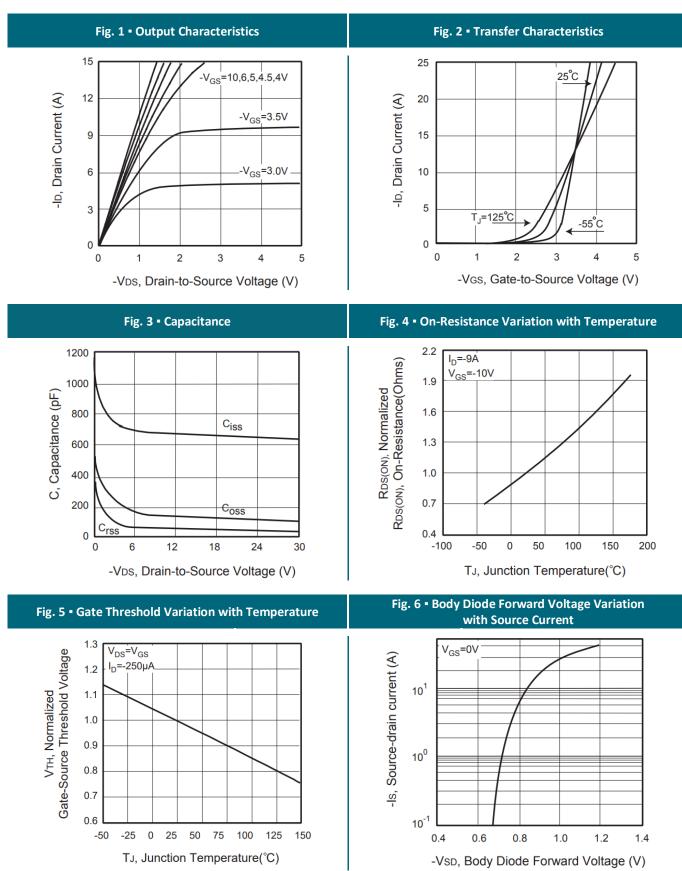
4: Guaranteed by design, not subject to production testing.



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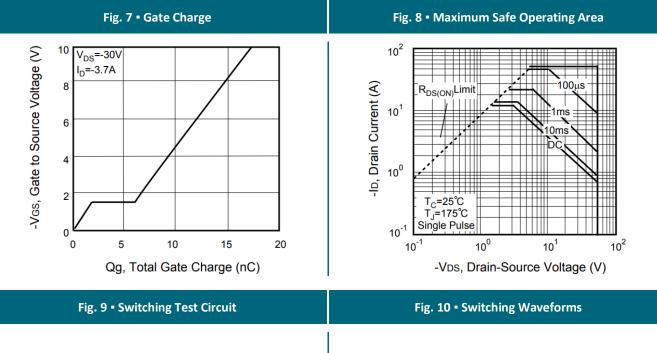
REFERENCE DATA ▲ TYPICAL DEVICE PERFORMANCE

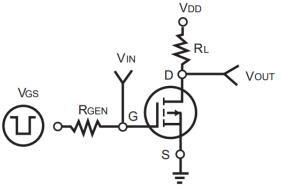




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REFERENCE DATA ▲ TYPICAL DEVICE PERFORMANCE





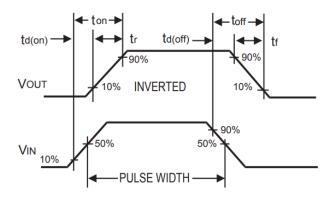
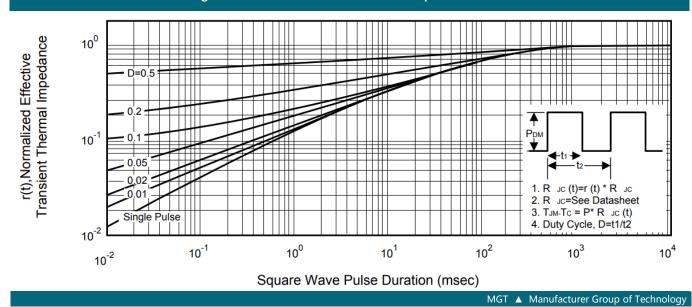


Fig. 11 • Normalized Thermal Transient Impedance Curve

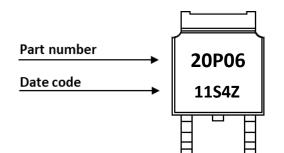


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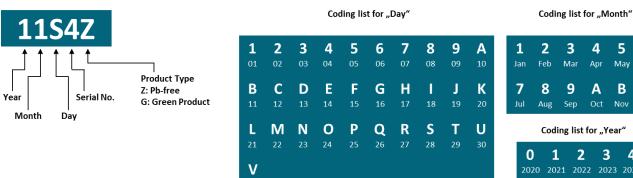






DATE CODE

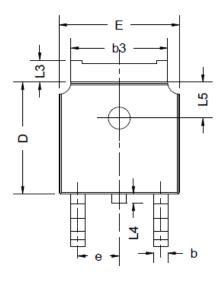
Example: 11S4Z

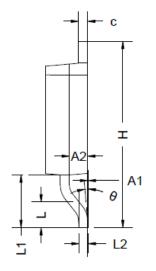


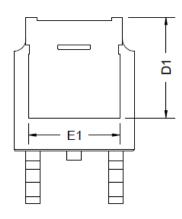
5 6 С В Coding list for "Year" 3 4 5 9 6 7 8



PACKAGE OUTLINE







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f

Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)		Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
А	2.20	2.30	2.38		е		2.286 BSC	
A1	0.00	-	0.20		н	9.40	10.10	10.50
A2	0.90	1.07	1.17		L	1.38	1.50	1.75
b	0.68	0.78	0.90 L1 2.90 RE		2.90 REF			
b3	5.23	5.33	5.46		L2		0.51 BSC	
С	0.43	0.53	0.61		L3	0.88	-	1.28
D	5.98	6.10	6.22		L4	0.50		1.00
D1		5.30 REF			L5	1.65	1.80	1.95
E	6.40	6.60	6.73		θ	0°	-	8°
E1	4.63	-	-					

ORDERING INFORMATION

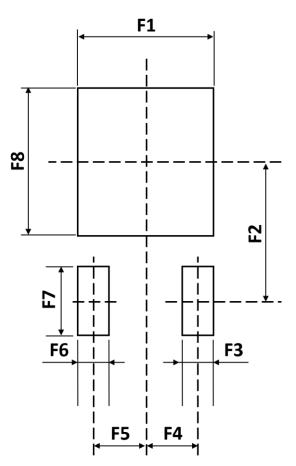
Part Number	Package	Packing	Reel Qty.	Inner Box Qty.	Outer Box Qty.
CEU20P06	TO252 (DPAK)	Reel	2,500pcs	5,000pcs	40,000pcs

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RECOMMENDED PAD LAYOUT



Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)	Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
F1	-	6.00	-	F5	-	2.29	-
F2	-	6.25	-	F6	-	1.40	-
F3	-	1.40	-	F7	-	3.00	-
F4	-	2.29	-	F8	-	6.50	-

Notes:

1. The suggested land pattern dimensions have been provided for reference only.

2. For further information, please reference document IPC-7351A.

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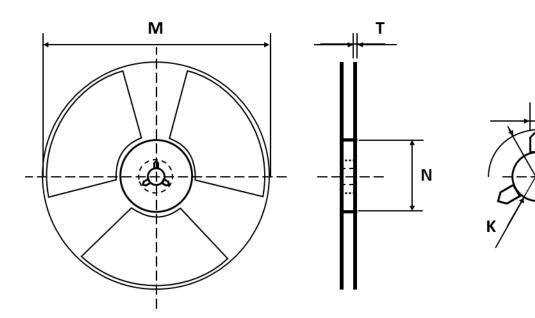


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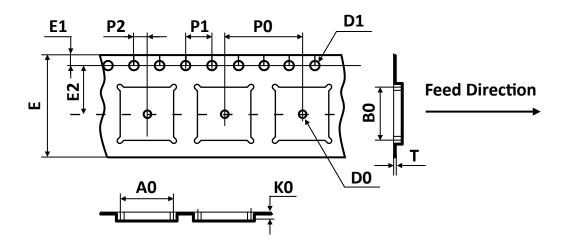


REEL DIMENSIONS All dimensions in mm



Tape Size	Reel Size	М	N	т	Н	К	S
	16mm Ø330	Ø330.00	Ø100.00	2.10	22.00	13.00	2.00
16mm		±2.00	±0.50	±0.20	±0.50	+0.50	+0.50
		±2.00	±0.50	±0.20	±0.50	-0.20	-0.20

TAPE DIMENSIONS All dimensions in mm



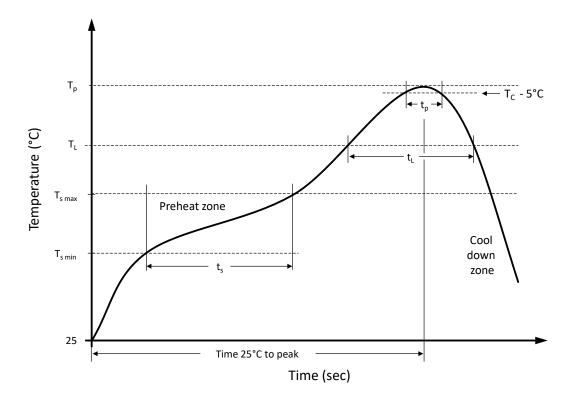
Package	A0	B0	К0	D0	D1	E	E1	E2	P0	P1	P2	т
TO252	6.90	10.50	2.70	1.50	1.50	16.00	1.75	7.50	8.00	4.00	2.00	0.30
(DPAK)	±0.10	±0.10	±0.10	MIN	±0.10	+0.30 -0.20	±0.10	±0.10	±0.10	±0.10	±0.10	±0.05



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RECOMMENDED REFLOW SOLDERING PROFILE



Recommended reflow soldering conditions ▲ **Refer to JEDEC J-STD-020E**

Profile Features		Sn-Pb Eutetic Assembly	Pb-Free Assembly
Preheat temperature min.	T_{smin}	100 °C	150 °C
Preheat temperature max.	$T_{s max}$	150 °C	200 °C
Preheat time t_s from $T_{s min}$ to $T_{s max}$	ts	120 seconds	120 seconds
Ramp-up rate (T _L to T _p)		max. 3 °C/second	max. 3 °C/second
Liquidous temperature	ΤL	183 °C	217 °C
Time t_L maintained above T_L	t∟	150 seconds max.	150 seconds max.
Peak package body temperature	Tp	235°C	260°C
Timeframe of within 5°C below and up to max actual peak body temperature	tp	20 seconds max.	30 seconds max.
Ramp-down rate (T_L to T_p)		max. 6 °C/second	max. 6 °C/second
Time 25°C to peak temperature		max. 6 minutes	max. 8 minutes

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REVISION TABLE

Revision	Date	Status	Notes
001	30/09/2022	Initial release	Initial publication

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